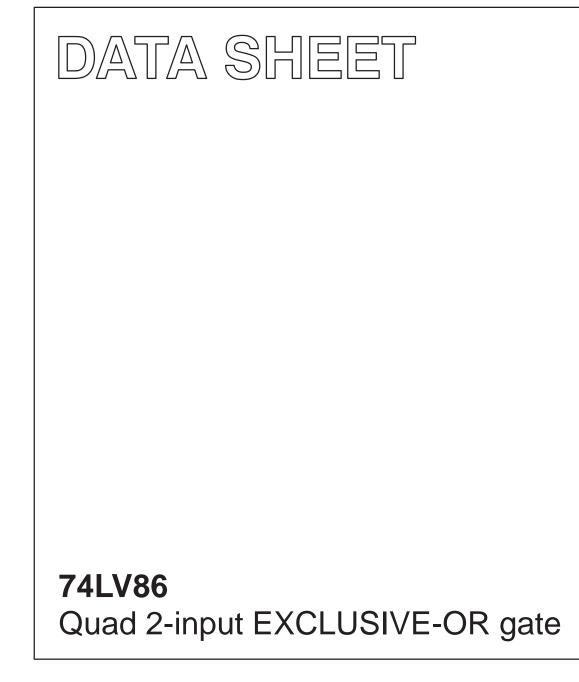
INTEGRATED CIRCUITS



Product specification Supersedes data of 1997 Feb 03 IC24 Data Handbook 1998 Apr 20



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74LV86

FEATURES

- Wide Operating voltage: 1.0 to 5.5 V
- Optimized for low voltage applications: 1.0 to 3.6 V
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Typical V_{OLP} (output ground bounce) < 0.8 V at V_{CC} = 3.3 V, $T_{amb} = 25^{\circ}C$
- Typical V_{OHV} (output V_{OH} undershoot) > 2 V at V_{CC} = 3.3 V, $T_{amb} = 25^{\circ}C$
- Output capability: standard
- I_{CC} category: SSI

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5$ ns

DESCRIPTION

The 74LV86 is a low-voltage Si-gate CMOS device that is pin and function compatible with 74HC/HCT86.

The 74LV86 provides the 2-input EXCLUSIVE-OR function.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay nA, nB to nY	$\begin{array}{l} C_L = 15 \text{ pF}; \\ V_{CC} = 3.3 \text{ V} \end{array}$	11	ns
CI	Input capacitance		3.5	pF
C _{PD}	Power dissipation capacitance per gate	$V_I = GND$ to V_{CC}^1	30	pF

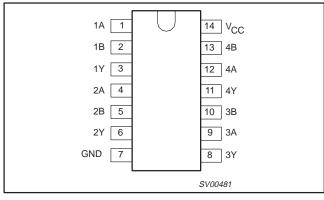
NOTE:

 C_{PD} is used to determine the dynamic power dissipation (P_D in $\mu W)$ 1. $\begin{array}{l} \mathsf{P}_{D} = \mathsf{C}_{PD} \times \mathsf{V}_{CC}{}^2 \times \mathsf{f}_i + \mathop{\textstyle\sum}\limits_{} (\mathsf{C}_L \times \mathsf{V}_{CC}{}^2 \times \mathsf{f}_o) \text{ where:} \\ \mathsf{f}_i = \mathsf{input} \text{ frequency in MHz; } \mathsf{C}_L = \mathsf{output} \text{ load capacitance in pF;} \\ \mathsf{f}_o = \mathsf{output} \text{ frequency in MHz; } \mathsf{V}_{CC} = \mathsf{supply voltage in V;} \\ \mathop{\textstyle\sum}\limits_{} (\mathsf{C}_L \times \mathsf{V}_{CC}{}^2 \times \mathsf{f}_o) = \mathsf{sum of the outputs.} \end{array}$

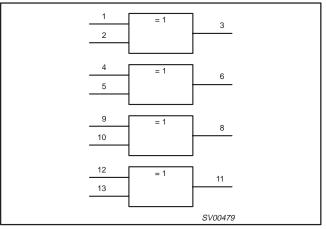
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
14-Pin Plastic DIL	–40°C to +125°C	74LV86 N	74LV86 N	SOT27-1
14-Pin Plastic SO	–40°C to +125°C	74LV86 D	74LV86 D	SOT108-1
14-Pin Plastic SSOP Type II	–40°C to +125°C	74LV86 DB	74LV86 DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV86 PW	74LV86PW DH	SOT402-1

PIN CONFIGURATION



LOGIC SYMBOL (IEEE/IEC)

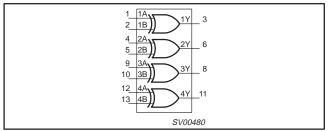


74LV86

PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1, 4, 9, 12	1A – 4A	Data inputs
2, 5, 10, 13	1B – 4B	Data inputs
3, 6, 8, 11	1Y – 4Y	Data outputs
7	GND	Ground (0 V)
14	V _{CC}	Positive supply voltage

LOGIC SYMBOL



RECOMMENDED OPERATING CONDITIONS

FUNCTION TABLE

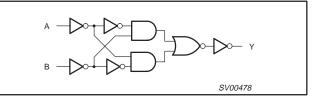
INP	INPUTS					
nA	nB	nY				
L	L	L				
L	Н	Н				
н	L	н				
н	Н	L				

NOTES:

H = HIGH voltage level

L = LOW voltage level

LOGIC DIAGRAM (ONE GATE)



SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1	1.0	3.3	5.5	V
VI	Input voltage		0		V _{CC}	V
Vo	Output voltage		0		V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times	$\begin{array}{l} V_{CC} = 1.0 V \text{ to } 2.0 \text{ V} \\ V_{CC} = 2.0 V \text{ to } 2.7 \text{ V} \\ V_{CC} = 2.7 V \text{ to } 3.6 \text{ V} \\ V_{CC} = 3.6 V \text{ to } 5.5 \text{ V} \end{array}$			500 200 100 50	ns/V

NOTE:

1. The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 5.5 V.

ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
± I _{IK}	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5 V$	20	mA
± I _{OK}	DC output diode current	$V_{\rm O}$ < -0.5 or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5V	50	mA
± I _O	DC output source or sink current – standard outputs	$-0.5V < V_{O} < V_{CC} + 0.5V$	25	mA
±I _{GND} , ±I _{CC}	DC V _{CC} or GND current for types with – standard outputs		50	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package – plastic DIL – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

					LIMITS	_		
SYMBOL	PARAMETER	TEST CONDITIONS	-40	°C to +8	5°C	-40°C to	o +125°C] υνιτ
			MIN	TYP ¹	MAX	MIN	MAX	
		V _{CC} = 1.2 V	0.9			0.9		
VIH	HIGH level Input	$V_{CC} = 2.0 V$	1.4			1.4		
ЧН	voltage	V _{CC} = 2.7 to 3.6 V	2.0			2.0] `
		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$	0.7 * V _{CC}			0.7 * V _{CC}		
		V _{CC} = 1.2 V			0.3		0.3	
VIL	LOW level Input	V _{CC} = 2.0 V			0.6		0.6	
٩L	voltage	V _{CC} = 2.7 to 3.6 V			0.8		0.8	1 `
		V _{CC} = 4.5 to 5.5			0.3 * V _{CC}		0.3 * V _{CC}	1
		V_{CC} = 1.2 V; V_I = V_{IH} or V_{IL} ; $-I_O$ = 100 μ A		1.2				
		$V_{CC} = 2.0 \text{ V}; \text{ V}_{I} = V_{IH} \text{ or } \text{V}_{IL;} - I_{O} = 100 \mu \text{A}$	1.8	2.0		1.8		-
V _{OH}	HIGH level output voltage; all outputs	$V_{CC} = 2.7 \text{ V}; \text{ V}_{I} = V_{IH} \text{ or } \text{V}_{IL;} - \text{I}_{O} = 100 \mu \text{A}$	2.5	2.7		2.5		V
		$V_{CC} = 3.0 \text{ V}; \text{ V}_{I} = \text{V}_{IH} \text{ or } \text{V}_{IL;} - \text{I}_{O} = 100 \mu \text{A}$	2.8	3.0		2.8		1
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = V_{IH} \text{ or } \text{V}_{IL}; -I_{O} = 100 \mu \text{A}$	4.3	4.5		4.3		1
V _{ОН}	HIGH level output voltage;	V_{CC} = 3.0 V; V_{I} = V_{IH} or V_{IL} ; $-I_{O}$ = 6mA	2.40	2.82		2.20		v
VОН	STANDARD outputs	V_{CC} = 4.5 V; V_{I} = V_{IH} or V_{IL} ; $-I_{O}$ = 12mA	3.60	4.20		3.50		
		V_{CC} = 1.2 V; V_{I} = V_{IH} or $V_{IL;}$ I_{O} = 100 μA		0				
	LOW level output	V_{CC} = 2.0 V; V_{I} = V_{IH} or $V_{IL;}$ I_{O} = 100 μA		0	0.2		0.2	
V _{OL}	voltage; all outputs	V_{CC} = 2.7 V; V_I = V_{IH} or V_{IL} ; I_O = 100 μ A		0	0.2		0.2	V
		V_{CC} = 3.0 V; V_{I} = V_{IH} or V_{IL} ; I_{O} = 100 μ A		0	0.2		0.2	
		V_{CC} = 4.5 V; V_{I} = V_{IH} or $V_{IL;}$ I_{O} = 100 μA		0	0.2		0.2	
V _{OL}	LOW level output voltage;	V_{CC} = 3.0 V; V_{I} = V_{IH} or V_{IL} ; I_{O} = 6mA		0.25	0.40		0.50	v
۰OL	STANDARD outputs	V_{CC} = 4.5 V; V_{I} = V_{IH} or $V_{IL;}$ I_{O} = 12mA		0.35	0.55		0.65	ľ
lı	Input leakage current	V_{CC} = 5.5 V; V_{I} = V_{CC} or GND			1.0		1.0	μA
I _{CC}	Quiescent supply current; SSI	$V_{CC} = 5.5V; V_I = V_{CC} \text{ or GND}; I_O = 0$			20.0		40	μA
ΔI_{CC}	Additional quiescent supply current per input	V_{CC} = 2.7 V to 3.6 V; $V_{\rm I}$ = V_{CC} –0.6 V			500		850	μΑ

NOTE:

1. All typical values are measured at $T_{amb} = 25^{\circ}C$.

AC CHARACTERISTICS

GND = 0V; $t_r = t_f \le 2.5ns$; C_L = 50pF; R_L = 1K Ω

		CONDITION											
SYMBOL	PARAMETER	WAVEFORM	CONDITION		40 to +85 °	С	–40 to +	⊦125 °C	UNIT				
			V _{CC} (V)	MIN	TYP ¹	MAX	MIN	MAX					
			1.2		70								
			2.0		24	32		41					
t _{PHL} /t _{PLH}	Propagation delay nA, nB to nY	Figure 1	2.7		18	24		30	ns				
			3.0 to 3.6		13 ²	19		24					
								4.5 to 5.5			16		20

NOTES:

1. Unless otherwise stated, all typical values are measured at $T_{amb} = 25^{\circ}C$.

2. Typical values are measured at V_{CC} = 3.3 V.

74LV86

AC WAVEFORMS

 V_M = 1.5 V at $V_{CC} \ge 2.7$ V and ≤ 3.6 V; V_M = 0.5 \times V_{CC} at $V_{CC} < 2.7$ V and ≥ 4.5 V; V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

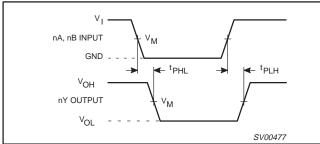


Figure 1. Input (nA, nB) to output (nY) propagation delays and the output transition times.

TEST CIRCUIT

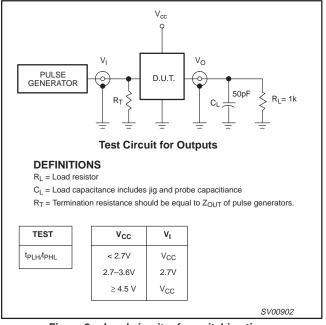
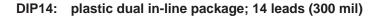
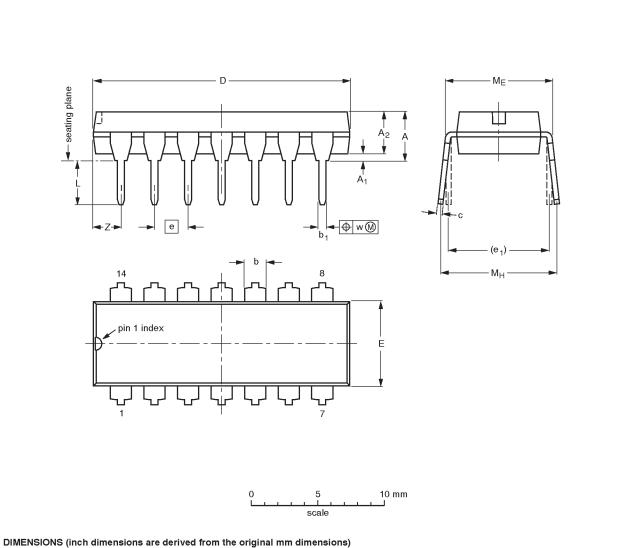


Figure 2. Load circuitry for switching times.





UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	с	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

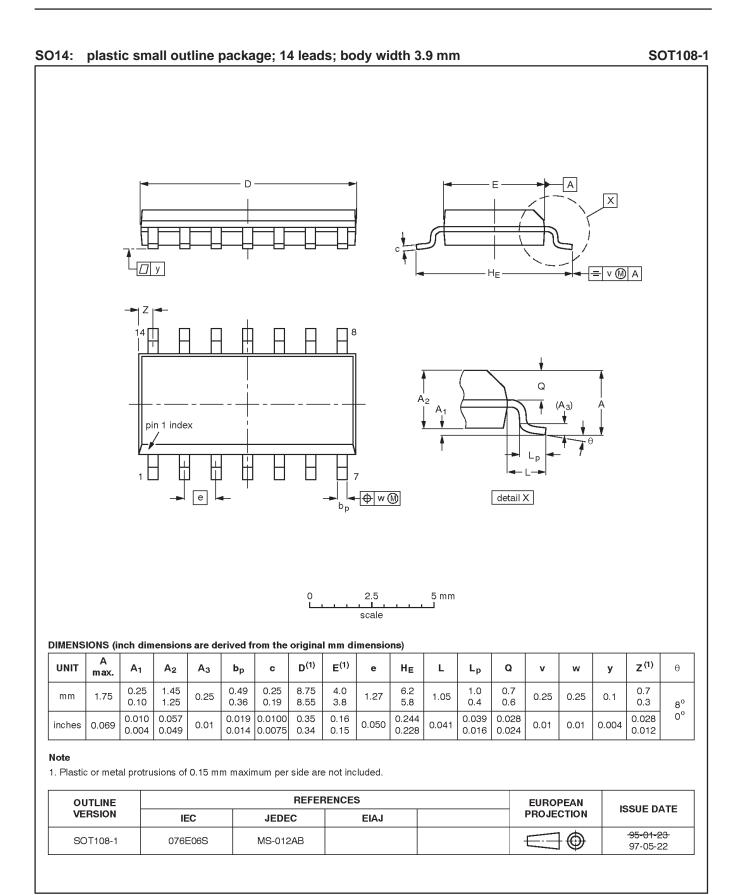
OUTLINE		REFER	ENCES			
VERSION	IEC	JEDEC	EIAJ	PROJECTION ISSUE DATE		
SOT27-1	050G04	MO-001AA			-92-11-17 95-03-11	

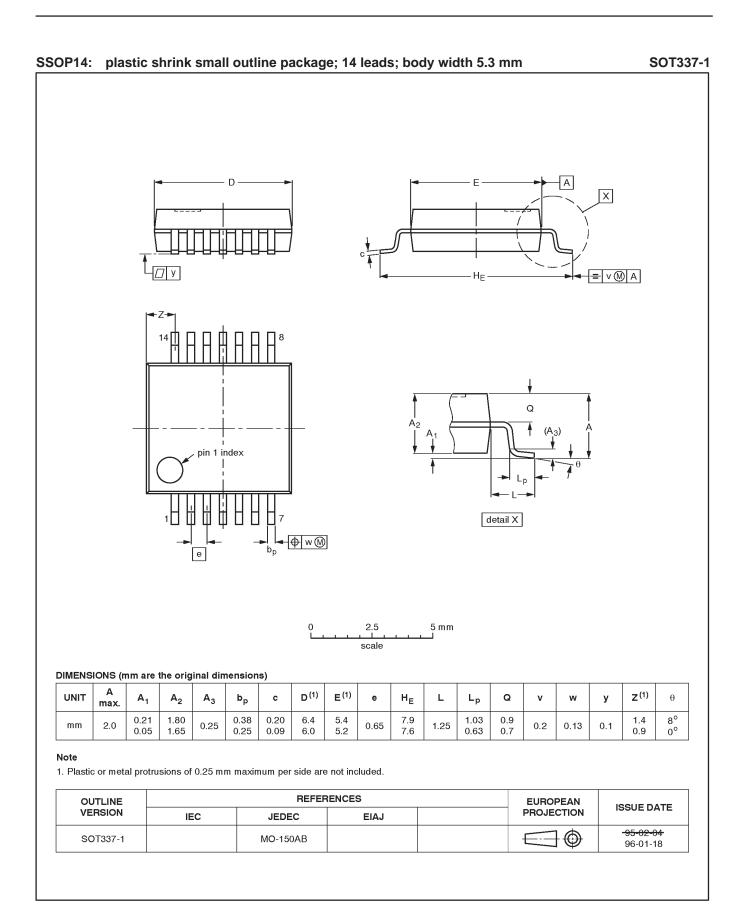
6

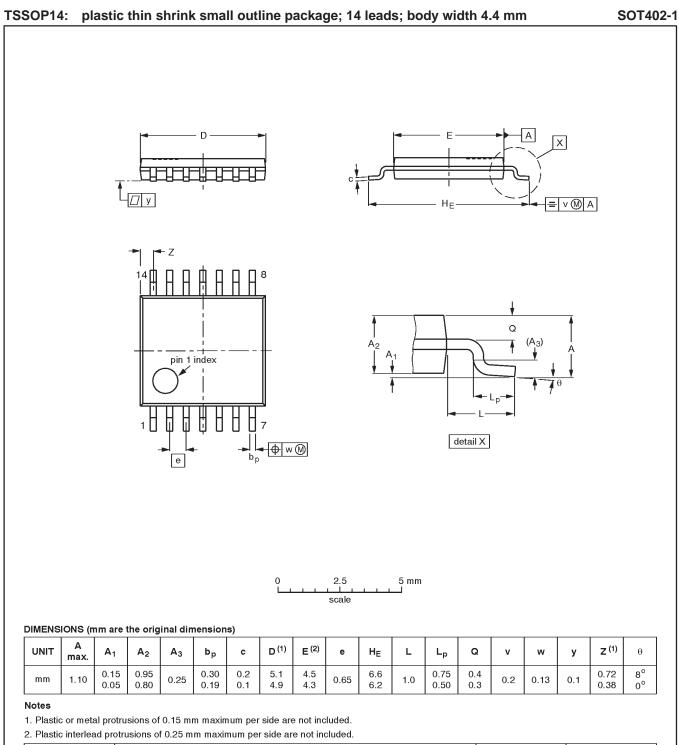
Product specification

74LV86

SOT27-1







OUTLINE		REFER	ENCES			
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1550E DATE	
SOT402-1		MO-153			- 94-07-12 95-04-04	

74LV86

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
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[1] Please consult the most recently issued datasheet before initiating or completing a design.

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